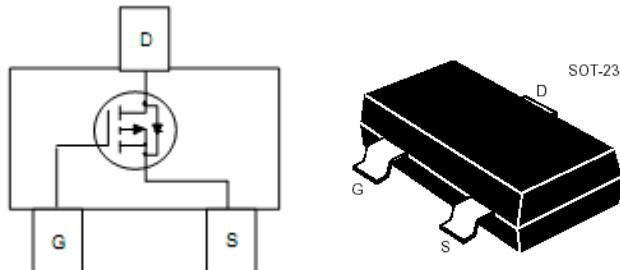




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SOT-23 場效應晶體管(SOT-23 Field Effect Transistors)

**P-Channel Enhancement-Mode MOS FETs****P 沟道增强型 MOS 场效应管****■MAXIMUM RATINGS 最大額定值**

Characteristic 特性參數	Symbol 符號	Max 最大值	Unit 單位
Drain-Source Voltage 漏極-源極電壓	$BV_{DSS}$	-30	V
Gate- Source Voltage 柵極-源極電壓	$V_{GS}$	$\pm 20$	V
Drain Current (continuous) 漏極電流-連續	$I_D$	-4.1	A
Drain Current (pulsed) 漏極電流-脉冲	$I_{DM}$	-16	A
Total Device Dissipation 總耗散功率	$P_D$	1400	mW
TA=25°C 環境溫度為 25°C			
Junction 結溫	$T_J$	150	°C
Storage Temperature 儲存溫度	$T_{stg}$	-55 to +150	°C



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## ■ELECTRICAL CHARACTERISTICS 電特性

(T<sub>A</sub>=25°C unless otherwise noted 如無特殊說明，溫度為 25°C)

Characteristic 特性參數	Symbol 符號	Min 最小值	Typ 典型值	Max 最大值	Unit 單位
Drain-Source Breakdown Voltage 漏極-源極擊穿電壓(I <sub>D</sub> = -250uA, V <sub>GS</sub> =0V)	BVDSS	-30	—	—	V
Gate Threshold Voltage 柵極開啓電壓(I <sub>D</sub> = -250uA, V <sub>GS</sub> = V <sub>DS</sub> )	V <sub>GS(th)</sub>	-1	—	-2	V
Diode Forward Voltage Drop 內附二極管正向壓降(I <sub>S</sub> = -1A, V <sub>GS</sub> =0V)	V <sub>SD</sub>	—	—	-1	V
Zero Gate Voltage Drain Current 零柵壓漏極電流(V <sub>GS</sub> =0V, V <sub>DS</sub> = -24V) (V <sub>GS</sub> =0V, V <sub>DS</sub> = -24V, T <sub>A</sub> =55°C)	I <sub>DSS</sub>	—	—	-1 -5	uA
Gate Body Leakage 柵極漏電流(V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V)	I <sub>GSS</sub>	—	—	±100	nA
Static Drain-Source On-State Resistance 静态漏源導通電阻(I <sub>D</sub> = -4.1A, V <sub>GS</sub> = -10V)	R <sub>DS(ON)</sub>	—	55	65	mΩ
Static Drain-Source On-State Resistance 静态漏源導通電阻(I <sub>D</sub> = -2A, V <sub>GS</sub> = -4.5V)	R <sub>DS(ON)</sub>	—	75	95	mΩ
Input Capacitance 輸入電容 (V <sub>GS</sub> =0V, V <sub>DS</sub> = -15V, f=1MHz)	C <sub>ISS</sub>	—	260	—	pF
Output Capacitance 輸出電容 (V <sub>GS</sub> =0V, V <sub>DS</sub> = -15V, f=1MHz)	C <sub>OSS</sub>	—	37	—	pF
Turn-ON Time 开啓時間 (V <sub>DS</sub> = -15V, V <sub>GS</sub> = -10V, R <sub>GEN</sub> =6Ω)	t <sub>(on)</sub>	—	6	—	ns
Turn-OFF Time 关斷時間 (V <sub>DS</sub> = -15V, V <sub>GS</sub> = -10V, R <sub>GEN</sub> =6Ω)	t <sub>(off)</sub>	—	20	—	ns

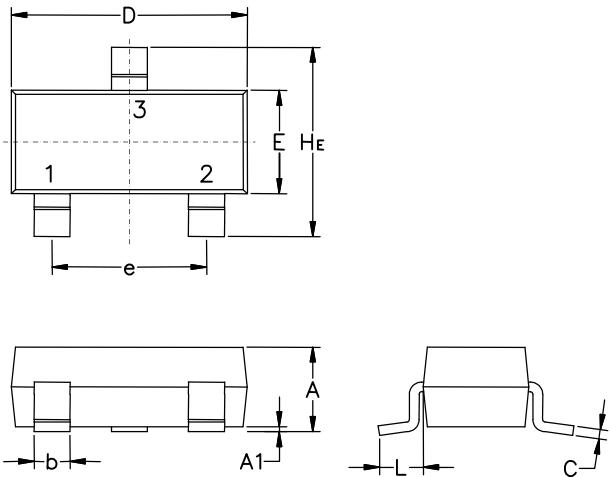
Pulse Width≤300 μ s; Duty Cycle≤2.0%



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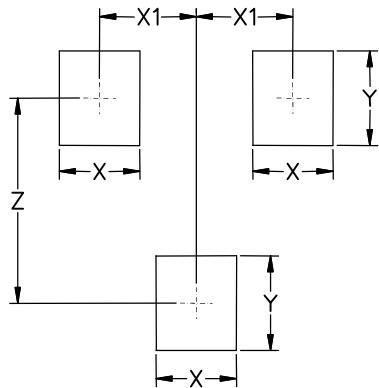
LM3407

### SOT-23 Package Outline & Dimensions



Symbol	Millimeters			Inches		
	Min.	Nom.	Max.	Min.	Nom.	Max.
A	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.15	0.18	0.020
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.081
L	0.35	0.54	0.69	0.014	0.021	0.029
H <sub>E</sub>	2.10	2.40	2.64	0.083	0.094	0.104

### Soldering Footprint



Symbol	Millimeters	Inches
X	0.80	0.031
X1	0.95	0.037
Y	0.90	0.035
Z	2.00	0.079

Shanghai Leiditech Electronic Co.,Ltd  
Email: sale1@leiditech.com  
Tel : +86- 021 50828806  
Fax : +86- 021 50477059

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